

Study of Variation of Rise in Temperature with Operating Frequency

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ABSTRACT

In this paper, we presents about the variation of rise in temperature with operating frequency. Microwave ovens, microwave drying machine useful in paper industries etc. have been designed utilizing this temperature loss. Thus, microwave temperature becomes power tools for industrial and commercial applications and also for the study of some basic properties of materials. For the calculation of this rise of temperature and its dependence of geometry of the structure and operating frequency.

KEYWORDS: MSL, VSWR, MICROWAVE, COUPLERS.

I. INTRODUCTION

The presence of conduction strip and dielectric substrate causes heating effect or loss of energy in terms of temperature. It is important to study such temperature during the propagation of microwave in giga hertz range of frequency for designing the structures as this rise in temperature also limits the average power of the microstripline. Microwave ovens, microwave drying machine useful in paper industries etc. have been designed utilizing this temperature loss. Thus, microwave temperature becomes power tools for industrial and commercial applications and also for the study of some basic properties of materials. For the calculation of this rise of temperature and its dependence of geometry of the structure and operating frequency we have to study the characteristic impedance of the structure and the phase velocity of the wave traveling through the structure. The work involves the mathematical formulation of the problem and related computational work.

II. FORMULATION OF CHARACTERISTIC IMPEDANCES FOR EVEN AND ODD-MODES OF A MICROSTRIPLINE COUPLER

When a microstripline is placed parallel to another microstripline, coupler is formed. The power flowing in one line is coupled to the other line either in same direction or in opposite direction. The power flowing in same direction is referred to as even-mode of propagation. Power flowing in opposite direction is referred to as a odd-mode of propagation.



Where,

 V_P = phase velocity of the wave traveling along the microstrip line.

 C_P = capacitance per unit length of the line.

The capacitance of the line is the result of the combination of different components.

These are:

 C_{PP} = parallel plate capacitance between lower surface of the microstrip and

the ground plane and is given by

 $C_{PP} = [C_{reff}/c.\eta] . (w/h)$ ------(2)

 C_{PPU} = capacitance between the upper surface of the microstrip and the ground plane which is expressed as

 $C_{PPU} = (2/3) [C_{reff} / c.\eta] . (w/h)$

 $C_{\rm f}~$ = the fringing capacitance at the edges of the microstrip and is expressed

 $C_{f} = [C_{reff} / c.\eta] \cdot (2.7/Log4h/t)$

Where,

w = Microstrip width

 \mathcal{C}_{reff} = The effective dielectric constant of the medium

h = Height of the substrate

 η = Free space impedance = 377 Ω

c = The velocity of light in free space

 $= 3.0 \text{ X } 10^8 \text{ m/sec.}$

t = microstrip thickness.

Thus, the total capacitance (C_P) of the isolated microstrip structure is expressed as

$$C_{\rm P} = C_{\rm PP} + C_{\rm PPU} + C_{\rm f}$$

or $C_p = (C_{reff} / c.\eta) (w/h) + (2/3) (C_{reff} / c.\eta) (w/h) (C_{reff} / c.\eta).(2.7/Log4h/t)$ ---- (5)

This is the expression of the capacitance of the microstrip structure in terms of its geometric parameters. The phase velocity V_P can be calculated by the formula

$$V_P = c / \sqrt{\epsilon_{reff}}$$

For wide strip, $\mathcal{C}_{reff} \approx \mathcal{C}_r$, and

For narrow strip, $\varepsilon_{reff} \approx (\varepsilon_r + 1) / 2$

Where, C_r = relative dielectric constant.

From equations (3.3.1), (3.3.5) and (3.3.6), we get

 $Z_o = (\eta/\sqrt{C_{reff}}) \cdot [1/[(w/h) + (2w/3h) + (2.7/Log4h/t)]]$

The calculations made on the basis of this expression give the characteristics impedance, the propagation constant and other transmission parameters of a single microstrip structure.

When the second conductor is introduced close to the first one, the field distribution gets altered. In evenmode the electric field lines follow the pattern fairly similar to that of the isolated conductor. In case of oddmode, the two conductors are linked by the electric field lines.

----- (6)

----- (7)

----- (3)

----- (4)

The form of equation (7) obtained for the isolated microstrip line are also useful in calculating the characteristic impedance of microstrip coupler in even- and odd- modes. In the even-mode C_P is replaced by C_{Pe} and in the odd-mode by C_{Po} . Since the electric field lines are distributed in air and below the conductor in the dielectric substrate, the dielectric medium now becomes inhomogeneous. Due to in homogeneity the phase velocity (V_P) for the isolated case is replaced by V_{Pe} for the even- mode and V_{Po} for the odd- mode. Further in place of C_{reff} the effective dielectric constants (C_{reff})_{eo} are to be used for even and odd-modes separately. Similarly, Z_{oe} and Z_{oo} represent the characteristic impedances for even-and odd- modes respectively.

III. STUDY OF VARIATION OF RISE IN TEMPERATURE WITH OPERATING FREQUENCY

For such study exhaustive calculations have been performed to calculate thermal losses and subsequent rise in temperature. The results obtained have been placed in table 1 and graph between frequency and rise in temperature have been plotted both for even and odd-modes of propagation as shown in graph 1. It has been observed that thermal effects in case of even mode are larger than that in case of odd-mode. Also, with increase of frequency thermal effects increases both in case of even and odd-modes of propagation. Consequently, rise in temperature increases with frequency both for even and odd-modes.

w = 100 mms, $s = 100$ mms, $m = 100$ mms $t = 0.01$ mms						
f (GHz)	Even-mode			Ood-mode		
	$\alpha_d \ dB/m$	$\alpha_c dB/m$	ΔT °C	$\alpha_d dB/m$	$\alpha_c dB/m$	ΔT °C
3	0.025	0.69	9.27	0.021	0.88	12.06
6	0.026	0.63	8.47	0.023	0.82	11.26
12	0.029	0.59	7.68	0.023	0.75	10.34
18	0.028	0.57	7.67	0.025	0.71	9.82
21	0.031	0.56	7.56	0.028	0.72	9.69

Table No. 1: Variation of rise in temperature with operating frequency for even and odd-modes w = 100 mils s = 100 mils h = 100 mils t = 0.01 mils

Graph No. 1: Variation of rise in temperature with operating frequency for even and odd-modes w = 100 mils, s = 100 mils, h = 100 mils, t = 0.01 mils



IV. CONCLUSION

The thermal effects and rise in temperature can be controlled by changing these parameters. These are very useful in designing the machine useful for heating. Microwave oven, diathermy machine and other appliances useful in preserving agriculture products are based on this fact. Among several heating process this is also mode of heat transfer. In this mode heat is produced directly at the locations where loss of power occurs.

V. REFERENCES

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